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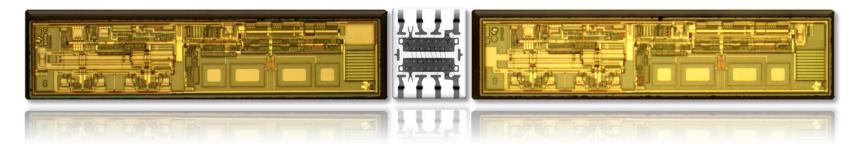


Wechat



ISO7221MDR

Dual Digital Isolators



Product Analysis Report

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